· · · · · · · · · · · · · · · · · · ·	Application No.	Applicant(s)
	09/490,502	ZHANG, HONGYUNG
Notice of Allowability	Examiner	Art Unit
	Tai Duong	2871
The MAILING DATE of this communication apperature All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT R of the Office or upon petition by the applicant. See 37 CFR 1.313	ears on the cover sheet with the (OR REMAINS) CLOSED in the correction or other appropriate communication is subjection is subjection.	the correspondence address is application. If not included cation will be mailed in due course. THIS
1. This communication is responsive to <u>Amendment 08/03/04</u>	<u>1</u> .	
2. The allowed claim(s) is/are <u>1-8 and 10-14</u> .		
3.   The drawings filed on are accepted by the Examine	r.	
<ul> <li>4.  Acknowledgment is made of a claim for foreign priority una)  All b)  Some* c)  None of the:</li> <li>1.  Certified copies of the priority documents have</li> <li>2.  Certified copies of the priority documents have</li> <li>3.  Copies of the certified copies of the priority do International Bureau (PCT Rule 17.2(a)).</li> <li>* Certified copies not received:</li> </ul>	e been received. e been received in Application N	lo
Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONN THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.		reply complying with the requirements
5. A SUBSTITUTE OATH OR DECLARATION must be subminFORMAL PATENT APPLICATION (PTO-152) which give		
6. CORRECTED DRAWINGS (as "replacement sheets") mus	st be submitted.	
(a) ☑ including changes required by the Notice of Draftsperson's Patent Drawing Review ( PTO-948) attached		
1) ☐ hereto or 2) ⊠ to Paper No./Mail Date <u>02/12/03</u> .		
(b) ☐ including changes required by the attached Examiner's Amendment / Comment or in the Office action of Paper No./Mail Date		
Identifying indicia such as the application number (see 37 CFR 1 each sheet. Replacement sheet(s) should be labeled as such in t		
7. DEPOSIT OF and/or INFORMATION about the depo attached Examiner's comment regarding REQUIREMENT		
Attachment(s)		
1. Notice of References Cited (PTO-892)	_	mal Patent Application (PTO-152)
<ol> <li>Notice of Draftperson's Patent Drawing Review (PTO-948)</li> <li>Information Disclosure Statements (PTO-1449 or PTO/SB/0</li> </ol>		il Date
Paper No./Mail Date	_	
<ol> <li>Examiner's Comment Regarding Requirement for Deposit of Biological Material</li> </ol>		atement of Reasons for Allowance

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## **REASONS FOR ALLOWANCE**

The following is an examiner's statement of reasons for allowance:

The rejections under 35 U.S. C. 112 of claims 3, 5, 7, 8, 12 and 13 are withdrawn in view of Applicant's remarks. See pages 11, 13 and 16-18 of the Remarks.

Claims 1-8 and 10-14 are allowed over the prior art of record.

Claim 1 is allowed because none of the prior art discloses or suggests the steps of performing arraying for plotting a master glass substrate into a plurality of blocks, further plotting each block into one, alternatively a plurality of device-forming regions, and forming a conductive film, an insulating film and a semiconductor film which constitute TFT (Thin Film Transistor) in the device-forming region; performing primary cutting for cutting the master glass substrate into the respective blocks to form a plurality of sub-TFT substrates; performing sub-TFT substrate processing for executing processing for each sub-TFT substrate in accordance with a device to be manufactured; and performing secondary cutting for cutting the sub-TFT substrate into each of the device-forming regions *in combination with* the step wherein the sub-TFT substrate processing step includes a step of forming a semiconductor film above the sub-TFT substrate.

Claim 4 is allowed because none of the prior art discloses or suggests the steps of performing arraying for plotting a master glass substrate into a plurality of blocks, further plotting each block into one, alternatively a plurality of device-forming regions, and forming a conductive film, an insulating film and a semiconductor film which constitute TFT (Thin Film Transistor) in the device-forming region; performing primary

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cutting for cutting the master glass substrate into the respective blocks to form a plurality of sub-TFT substrates; performing sub-TFT substrate processing for executing processing for each sub-TFT substrate in accordance with a device to be manufactured; and performing secondary cutting for cutting the sub-TFT substrate into each of the device-forming regions *in combination with* the step wherein the sub-TFT substrate processing step includes the steps of: forming a pixel electrode above the sub-TFT substrate; forming an orientation film for covering the pixel electrode; and joining a second substrate onto the sub-TFT substrate, and after the secondary cutting step, a step of sealing a liquid crystal between the sub-TFT substrate and the second substrate after the cutting is provided.

Claim 8 is allowed because none of the prior art discloses or suggests the steps of performing arraying for plotting a master glass substrate into a plurality of blocks, further plotting each block into one, alternatively a plurality of device-forming regions, and forming a conductive film, an insulating film and a semiconductor film which constitute TFT (Thin Film Transistor) in the device-forming region; performing primary cutting for cutting the master glass substrate into the respective blocks to form a plurality of sub-TFT substrates; performing sub-TFT substrate processing for executing processing for each sub-TFT substrate in accordance with a device to be manufactured; and performing secondary cutting for cutting the sub-TFT substrate into each of the device-forming regions *in combination with* the step wherein the sub-TFT substrate processing step, alignment is performed providing a fiducial mark on each sub-TFT substrate.

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The remaining claims are also allowed since they depend on the allowed claim 1.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Any inquiry concerning this communication should be directed to Tai Duong at telephone number (571) 272-2291.

The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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TVD

11/04

TOANTON PRIMARY EXAMINER